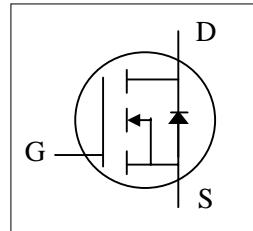




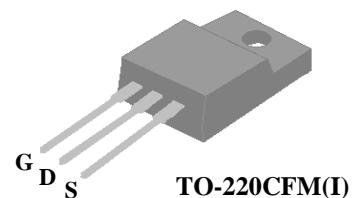
▼ Simple Drive Requirement

▼ Lower On-resistance

▼ RoHS Compliant & Halogen-Free



BV_{DSS}	100V
$R_{DS(ON)}$	6.4mΩ
I_D	60A



Description

AP95T10 series are from Advanced Power innovative design and silicon process technology to achieve the lowest possible on-resistance and fast switching performance. It provides the designer with an extreme efficient device for use in a wide range of power applications.

The TO-220CFM package is widely preferred for all commercial-industrial through hole applications. The mold compound provides a high isolation voltage capability and low thermal resistance between the tab and the external heat-sink.

Absolute Maximum Ratings@ $T_j=25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	100	V
V_{GS}	Gate-Source Voltage	± 20	V
$I_D @ T_c = 25^\circ\text{C}$	Drain Current, $V_{GS} @ 10\text{V}$	60	A
$I_D @ T_c = 100^\circ\text{C}$	Drain Current, $V_{GS} @ 10\text{V}$	43	A
I_{DM}	Pulsed Drain Current ¹	240	A
$P_D @ T_c = 25^\circ\text{C}$	Total Power Dissipation	60	W
T_{STG}	Storage Temperature Range	-55 to 175	°C
T_J	Operating Junction Temperature Range	-55 to 175	°C

Thermal Data

Symbol	Parameter	Value	Units
R_{thj-c}	Maximum Thermal Resistance, Junction-case	2.5	°C/W
R_{thj-a}	Maixmum Thermal Resistance, Junction-ambient	65	°C/W



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Electrical Characteristics@ $T_j=25^\circ C$ (unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=250\mu A$	100	-	-	V
$R_{DS(ON)}$	Static Drain-Source On-Resistance ²	$V_{GS}=10V, I_D=30A$	-	-	6.4	$m\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu A$	2	-	4	V
g_{fs}	Forward Transconductance	$V_{DS}=10V, I_D=30A$	-	105	-	S
I_{DSS}	Drain-Source Leakage Current	$V_{DS}=80V, V_{GS}=0V$	-	-	25	μA
I_{GSS}	Gate-Source Leakage	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	± 100	nA
Q_g	Total Gate Charge	$I_D=30A$	-	110	176	nC
Q_{gs}	Gate-Source Charge	$V_{DS}=80V$	-	19	-	nC
Q_{gd}	Gate-Drain ("Miller") Charge	$V_{GS}=10V$	-	58	-	nC
$t_{d(on)}$	Turn-on Delay Time	$V_{DS}=50V$	-	70	-	ns
t_r	Rise Time	$I_D=30A$	-	210	-	ns
$t_{d(off)}$	Turn-off Delay Time	$R_G=25\Omega$	-	300	-	ns
t_f	Fall Time	$V_{GS}=10V$	-	240	-	ns
C_{iss}	Input Capacitance	$V_{GS}=0V$	-	5870	9400	pF
C_{oss}	Output Capacitance	$V_{DS}=25V$	-	910	-	pF
C_{rss}	Reverse Transfer Capacitance	f=1.0MHz	-	375	-	pF
R_g	Gate Resistance	f=1.0MHz	-	2	-	Ω

Source-Drain Diode

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
V_{SD}	Forward On Voltage ²	$I_S=30A, V_{GS}=0V$	-	-	1.3	V
t_{rr}	Reverse Recovery Time	$I_S=30A, V_{GS}=0V$	-	75	-	ns
Q_{rr}	Reverse Recovery Charge	$dI/dt=100A/\mu s$	-	200	-	nC

Notes:

1.Pulse width limited by Max. junction temperature.

2.Pulse test

THIS PRODUCT IS SENSITIVE TO ELECTROSTATIC DISCHARGE, PLEASE HANDLE WITH CAUTION.

USE OF THIS PRODUCT AS A CRITICAL COMPONENT IN LIFE SUPPORT OR OTHER SIMILAR SYSTEMS IS NOT AUTHORIZED.

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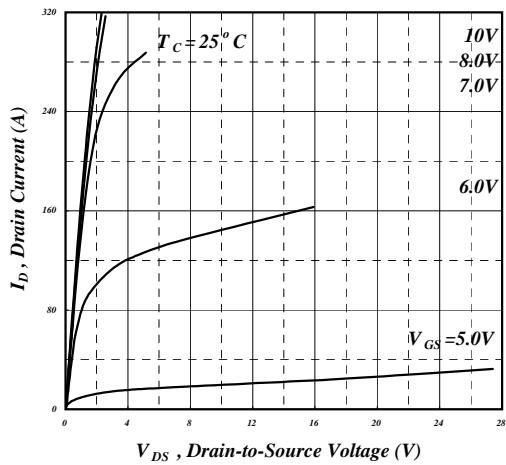


Fig 1. Typical Output Characteristics

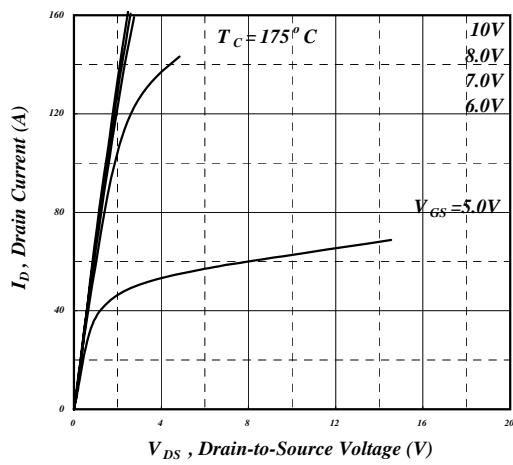


Fig 2. Typical Output Characteristics

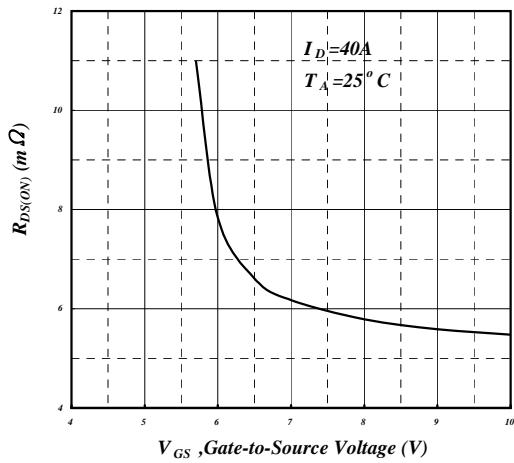


Fig 3. On-Resistance v.s. Gate Voltage

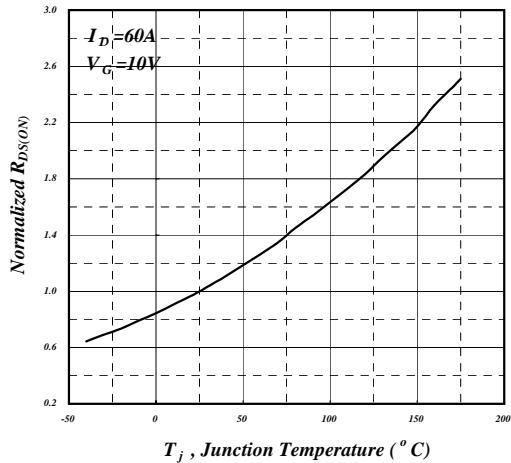


Fig 4. Normalized On-Resistance v.s. Junction Temperature

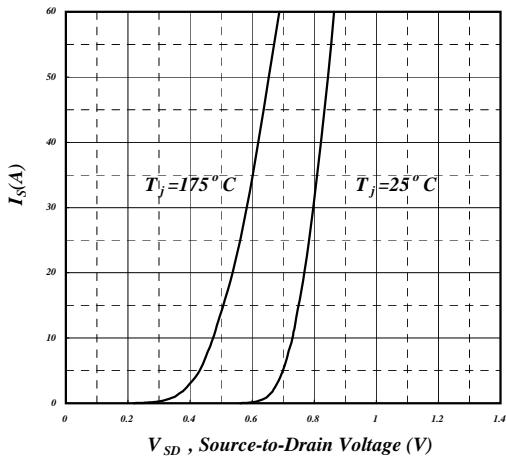


Fig 5. Forward Characteristic of Reverse Diode

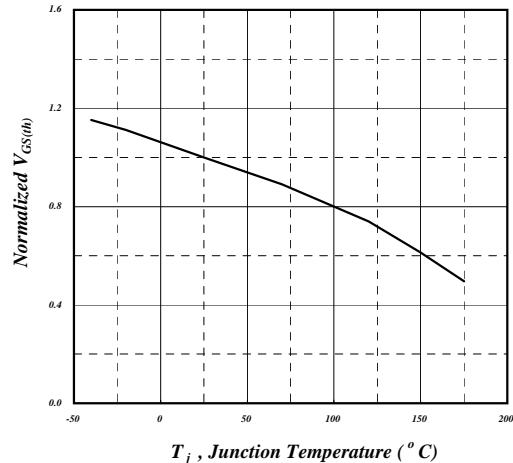


Fig 6. Gate Threshold Voltage v.s. Junction Temperature

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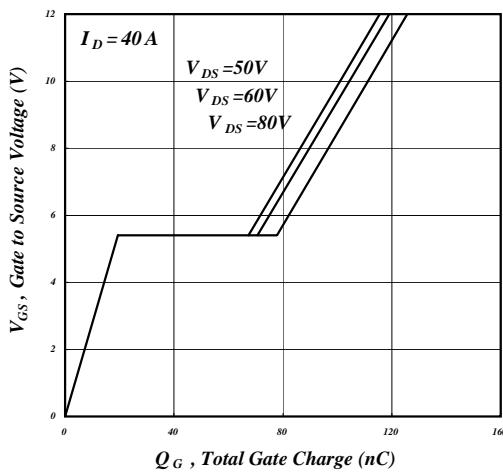


Fig 7. Gate Charge Characteristics

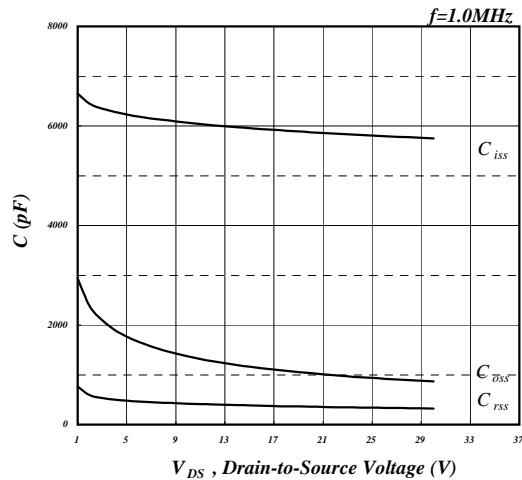


Fig 8. Typical Capacitance Characteristics

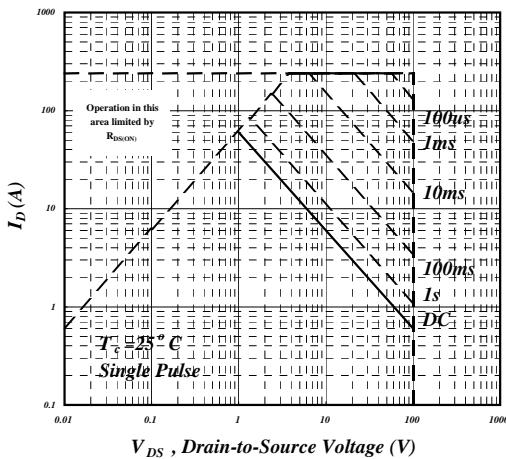


Fig 9. Maximum Safe Operating Area

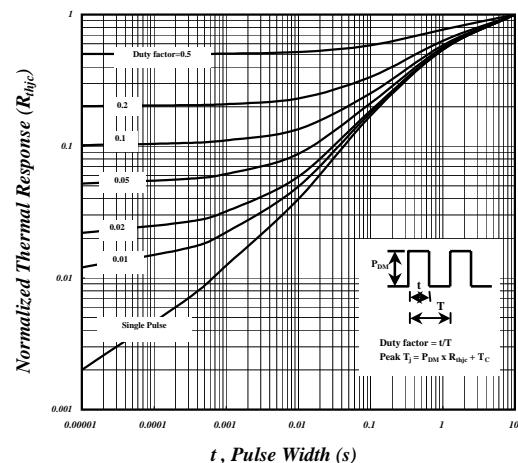


Fig 10. Effective Transient Thermal Impedance

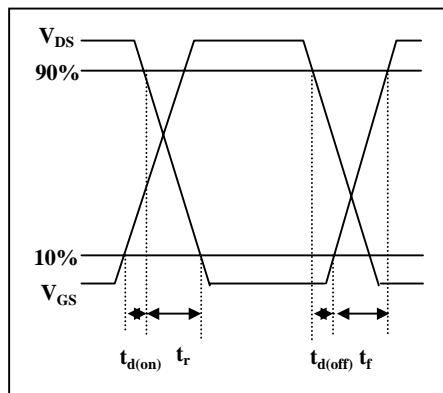


Fig 11. Switching Time Waveform

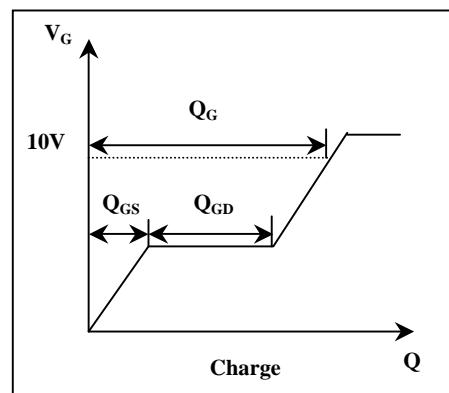


Fig 12. Gate Charge Waveform



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MARKING INFORMATION

